1. General description

NPN/PNP general-purpose double transistors in a leadless ultra small DFN1412-6 (SOT1268) Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: BC847RA PNP/PNP complement: BC857RA

2. Features and benefits

- Reduces component count
- Reduces pick and place costs
- Low package height of 0.5 mm
- AEC-Q101 qualified

3. Applications

- General-purpose switching and amplification
- · Mobile applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor; for the PNP transistor with negative polarity								
V _{CEO}	collector-emitter voltage	open base		-	-	45	V	
I _C	collector current			-	-	100	mA	
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	200	mA	
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		200	-	450		



45 V, 100 mA NPN/PNP general-purpose double transistors

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1		6 5 4
2	B1	base TR1	7 6	
3	C2	collector TR2	2 5	(TR1)
4	E2	emitter TR2		
5	B2	base TR2	[3] [0] [4]	1 2 3
6	C1	collector TR1	Transparent ton view	sym019
7	C1	collector TR1	Transparent top view DFN1412-6 (SOT1268)	
8	C2	collector TR2	,	

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BC847RAPN	DFN1412-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals; body: 1.4 mm x 1.2 mm x 0.47 mm	SOT1268		

7. Marking

Table 4. Marking codes

Type number	Marking code
BC847RAPN	A4

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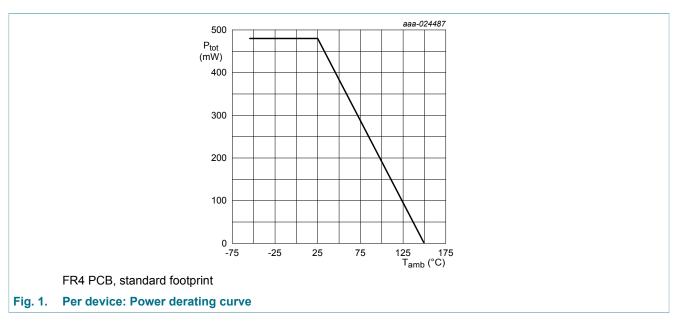
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or; for the PNP transistor wit	h negative polarity	'			
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	45	V
V _{EBO}	emitter-base voltage	open collector		-	6	V
I _C	collector current			-	100	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	200	mA
I _{BM}	peak base current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	325	mW
Per device		'	,		,	
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	480	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	r						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	385	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	261	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

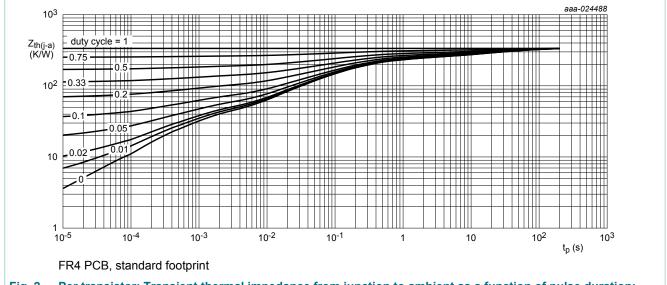


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	tor; for the PNP transistor	with negative polarity				
I _{CBO}	collector-base cut-off	V _{CB} = 30 V; I _E = 0 A; T _{amb} = 25 °C	-	-	15	nA
	current	V _{CB} = 30 V; I _E = 0 A; T _j = 150 °C	-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 ^{\circ}\text{C}$	-	-	100	nA
h _{FE}	DC current gain	V_{CE} = 5 V; I_{C} = 2 mA; T_{amb} = 25 °C	200	-	450	
V _{CEsat}	collector-emitter	I _C = 10 mA; I _B = 0.5 mA; T _{amb} = 25 °C	-	-	100	mV
	saturation voltage	I_C = 100 mA; I_B = 5 mA; T_{amb} = 25 °C	-	-	300	mV
V _{BEsat}	base-emitter saturation voltage	I_C = 10 mA; I_B = 0.5 mA; T_{amb} = 25 °C	-	760	-	mV
		I_C = 100 mA; I_B = 5 mA; T_{amb} = 25 °C	-	900	-	mV
V_{BE}	base-emitter voltage	V_{CE} = 5 V; I_{C} = 2 mA; T_{amb} = 25 °C	600	660	725	mV
		V_{CE} = 5 V; I_{C} = 10 mA; T_{amb} = 25 °C	-	710	820	mV
C _C	collector capacitance	V_{CB} = 10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C	-	-	4	pF
C _E	emitter capacitance	$V_{EB} = 0.5 \text{ V}; I_C = 0 \text{ A}; i_c = 0 \text{ A};$ f = 1 MHz; $T_{amb} = 25 \text{ °C}$	-	11	-	pF
		V_{EB} = -0.5 V; I_{C} = 0 mA; i_{c} = 0 mA; f = 1 MHz; f = 25 °C	-	10	-	pF
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 10 mA; f = 100 MHz; T_{amb} = 25 °C	100	-	-	MHz
NF	noise figure	$V_{CE} = 5 \text{ V; } I_{C} = 0.2 \text{ mA; } R_{S} = 2 \text{ k}\Omega;$ f = 1 MHz; $T_{amb} = 25 \text{ °C}$	-	-	10	dB

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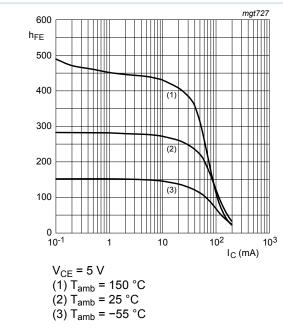


Fig. 3. NPN transistor: DC current gain as a function of collector current; typical values

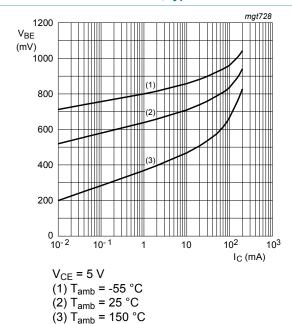


Fig. 5. NPN transistor: Base-emitter voltage as a function of collector current; typical values

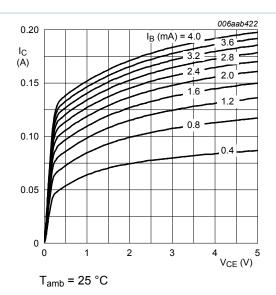
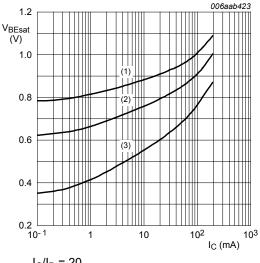


Fig. 4. NPN transistor: Collector current as a function of collector-emitter voltage; typical values

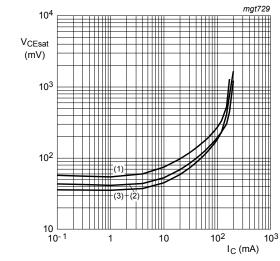


 $I_C/I_B = 20$ (1) $T_{amb} = -55 \,^{\circ}C$ (2) $T_{amb} = 25 \,^{\circ}C$ (3) $T_{amb} = 150 \,^{\circ}C$

Fig. 6. NPN transistor: Base-emitter saturation voltage as a function of collector current; typical values

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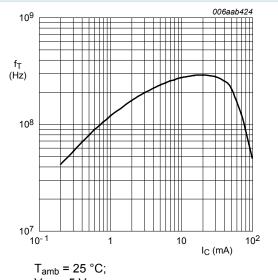
 $I_{\rm C}/I_{\rm B} = 20$

(1) T_{amb} = 150 °C

(2) $T_{amb} = 25 \, ^{\circ}C$

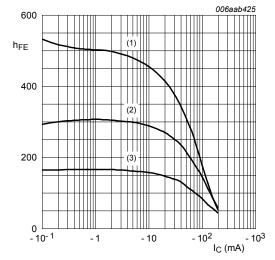
(3) $T_{amb} = -55 \, ^{\circ}C$

Fig. 7. **NPN** transistor: Collector-emitter saturation voltage as a function of collector current; typical values



 T_{amb} = 25 °C; V_{CE} = 5 V; f = 100 MHz

Fig. 8. NPN transistor: Transition frequency as a function of collector current; typical values

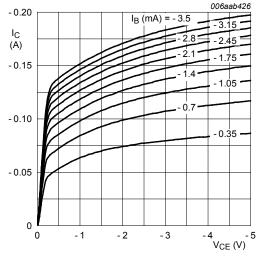


 $V_{CE} = -5 V$

(1) $T_{amb} = 150 \, ^{\circ}C$

(2) $T_{amb} = 25 \text{ °C}$ (3) $T_{amb} = -55 \text{ °C}$

PNP transistor: DC current gain as a function Fig. 9. of collector current; typical values



T_{amb} = 25 °C

Fig. 10. PNP transistor: Collector current as a function of collector-emitter voltage; typical values

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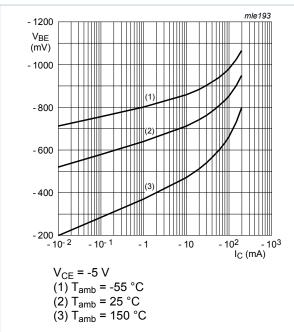


Fig. 11. PNP transistor: Base-emitter voltage as a function of collector current; typical values

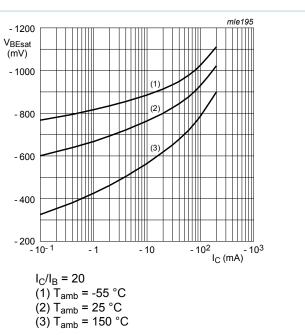


Fig. 12. PNP transistor: Base-emitter saturation voltage as a function of collector current; typical values

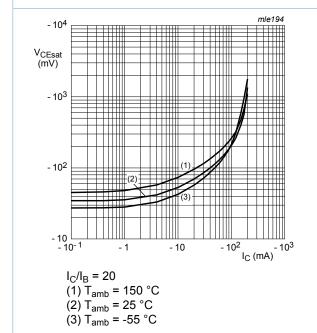


Fig. 13. PNP transistor: Collector-emitter saturation voltage as a function of collector current; typical values

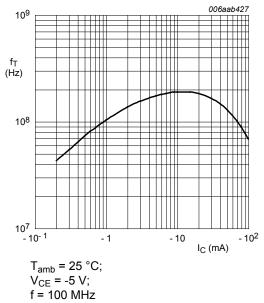


Fig. 14. PNP transistor: Transition frequency as a function of collector current; typical values

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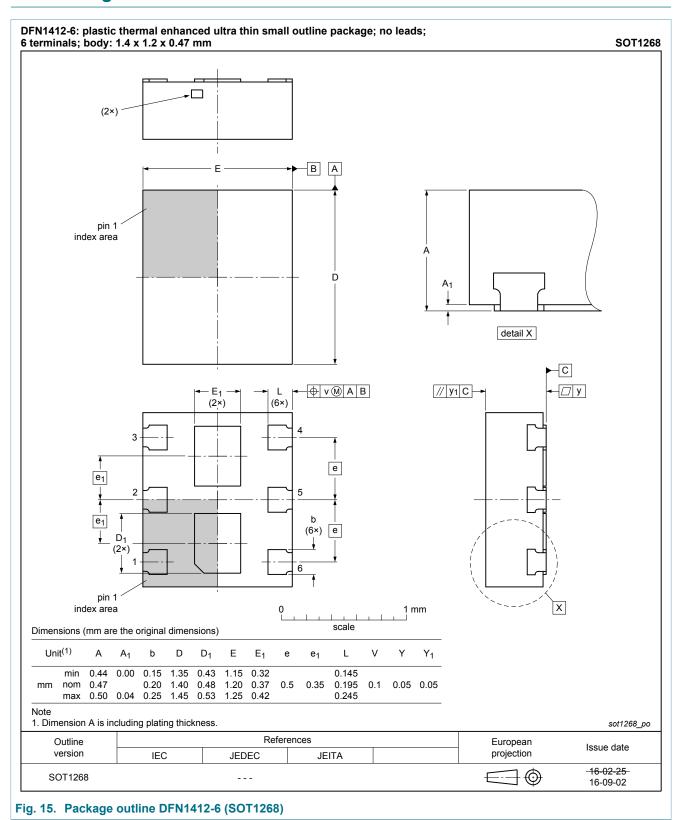
11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

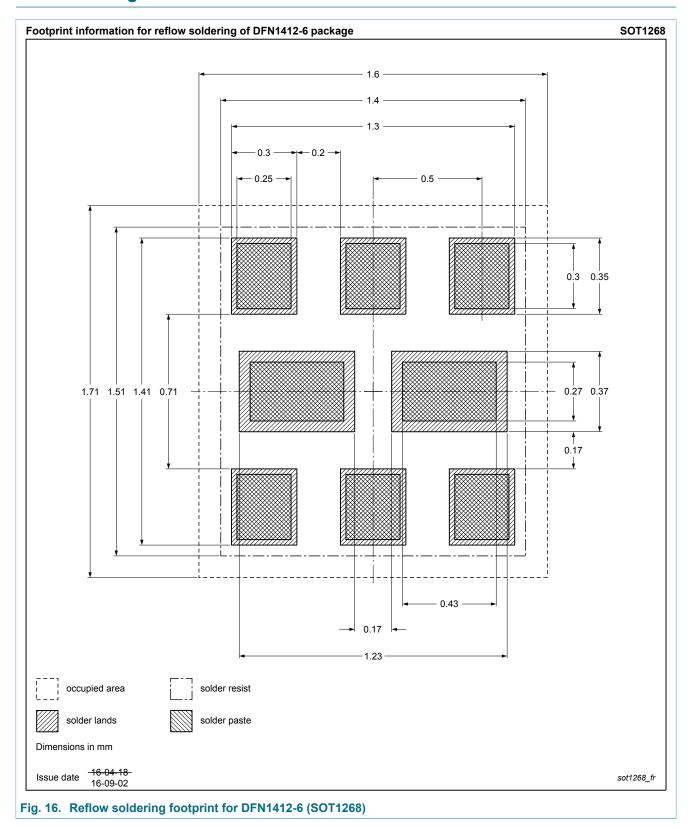
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12. Package outline



45 V, 100 mA NPN/PNP general-purpose double transistors

13. Soldering



45 V, 100 mA NPN/PNP general-purpose double transistors

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC847RAPN v.1	20170607	Product data sheet	-	-

45 V, 100 mA NPN/PNP general-purpose double transistors

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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